

T3AWG6K Series Data Sheet

Arbitrary Waveform Generator 2, 4 and 8 Channel Configuration





Sample Rate up to 12.32 GS/s in RF mode

- 16 Bit Vertical Resolution
- up to 5 V_{pp} Output Voltage and ±2.5 V HW Baseline Offset for a total output voltage window ±5 V or 10 V (50 Ohm)
- 4 GPts Waveform Memory per Channel
- Up to 32 Digital Channel in synchronous with Analog Generation
- Multifunctional solution instrument (AFG/AWG/DPG)

- Exceptional signal fidelity for developing quality products with a reduced design cycle.
- Unmatched wide output voltage window enables generating challenging in amplitude large-signal waveforms.
- Unmatched deep memory depth allows to store and reproduce complex pseudo-random waveforms for long play time testing.
- Mixed Signal Generation for debugging and validating analog and digital design.
- Arbitrary Function Generator, Arbitrary Waveform Generation and Digital Pattern Generation functionalities into one instrument.

Standard warranty is one year.

Key Specifications

Model	T3AWG6062	T3AWG6064	T3AWG6068	
Number of Analog Channels	2	4	8	
Vertical Resolution		16 bits		
Output Voltage	up to 5 V _{pp} and ± 2.5 V Baseline Hardware offset (50 Ohm into 50 Ohm)			
Sampling Rate	up to 6.16 GS/s variable clock (12.32 GS/s in RF mode) for AWG and 6.16 GS/S fixed in AFG			
Waveform Memory	4 Gpts per channel			
Digital Pattern Generator (DPG)	up to 8 Digital Channels up to 16 Digital Channels up to 32 Digital Channels			
Waveforms Sequencing	up to 16.384 waveforms, length granularity of 1 point (> 384 Pts.)			

AFG Operational Mode

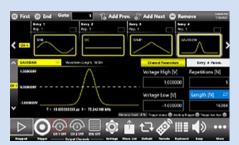
- Improved Direct Digital Synthesis (DDS) based technology
- Fixed Sampling Clock 6.16 GS/s



Arbitrary Function Generation (AFG functionality)

AWG Operational Mode

- Variable Clock True-Arbitrary Technology
- Variable Sampling Clock from 1 S/s to 6.16 GS/s (12.32 GS/s in RF mode)
- Mixed Signal Generation: 2/4/8 Analog Channels and 8/16/32 synchronized Digital Channels¹⁾



Arbitrary Waveform Generation (AWG functionality)



Digital Pattern Generation (DPG functionality)

Three different features on the same platform for a multifunctional generator

T3AWG6062, T3AWG6064 and T3AWG6068 are multifunctional generators that combines many functions in one instrument, i. e. Arbitrary Function Generator, Arbitrary Waveform Generator and Digital Pattern Generator.

These three-different functionalities are leveraging on the HW flexibility adopting two different technologies.

An improved Direct Digital Synthesis (DDS) based technology adopted when using the Function Generator (AFG) lets the user to change glitch free on-the-fly all the parameters preserving the waveform shape.

All control and setting are always one touch away: swipe gesture to change the channel, the carrier selection and have access to the modulation parameters, swipe into the waveform gallery to import a signal at a glance and use the touch-friendly virtual numeric keyboard to change parameters values.

The variable clock, true-arbitrary technology adopted when using the Arbitrary Waveform / Digital Pattern Generator lets the user to create complex waveforms of analog and digital pattern, insert them is a sequence,

apply loops, jumps and conditional branches. Digital output combined and synchronized with analog output signals represents an ideal tool to troubleshoot and validate digital design.

The waveform memory length of 4 GPts on each channel combined with number of waveforms entries up to 16,384 and the waveform repeat count higher then 4 10⁹ or infinite make the T3AWG6062, T3AWG6064 and T3AWG6068 the best-in-class waveform generators for the most demanding technical applications.

This innovative and disruptive hardware architecture combined with 16-bit vertical resolution and 4 Gpts waveform memory depth, makes the T3AWG6062, T3AWG6064 and T3AWG6068 the ideal generators for today's and tomorrow's test challenges.



¹⁾ See Digital Channel Selection Guide, page 16

Applications and Key Industries at a glance

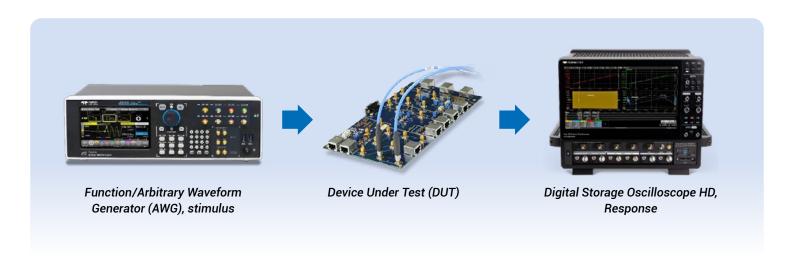
Multi-channel Stimulus-Response Testing

The T3AWG6K series arbitrary waveform generator delivers exceptional performance for creation of complex wideband waveforms. Up to 8 channels are available in a single instrument with 5 GHz bandwidth in @RF mode

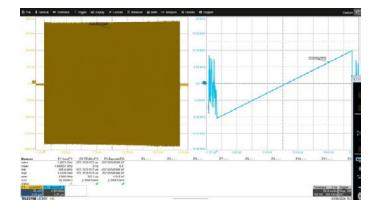
with 16-bit resolution and a sampling rate of 12.32 GS/s in @RF mode. Ideal for use in a Stimulus-Response measurement model with Digital Storage Oscilloscopes HD.

Different signal emulations

Emulation of	Stimulus-response testing case:
@perfect signal	DUT response behavior is not influenced by uncontrolled and unknown distortions
@real-world signal	DUT response behavior before any signal source can be available. (Playback of signals acquired using the oscilloscope and imported into the AWG)
@extreme condition signal	DUT response behavior in difficult conditions and corner cases (stress and margin tests)
@noise and interference signal	DUT response behavior with interference signals and noise added to the expected signal (noise and interference immunity)



Phase Coherence Baseband, IF and I/Q signals emulation

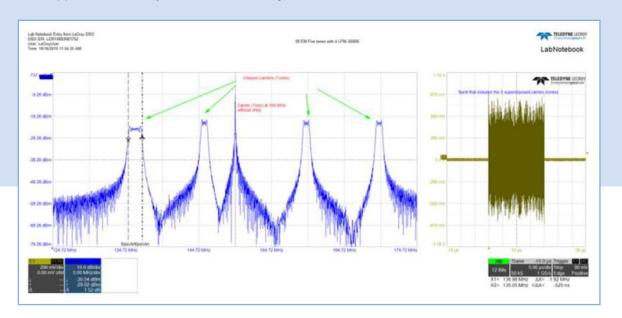


The T3AWG6K series can produce a wide range of modulations and signal scenarios. In fact, you can rely on the function generation operating mode (AFG) using improved direct digital synthesis (DDS) technology and a powerful and flexible waveform sequence in the arbitrary waveform generation mode (AWG) using variable-clock truearb technology. In addition, the ability to generate up to 32 digital channels synchronously with analog signals enables efficient and adaptive testing with complex signal emulation.

Complex Radio Frequency (RF) signal generation

Nowadays, RF engineers find it difficult to create the signals required for compliance and stress tests, simply because signals are becoming increasingly complex and require very precise phase related components. The T3AWG6K series arbitrary waveform generators can support all the today and tomorrow design and test

challenges. This is also thanks to the SW Waveform Editor utility which allow to create new arbitrary and complex waveforms in a simple, flexible, and affordable way and the ability to capture real-life waveforms directly acquired by real-time oscilloscopes.

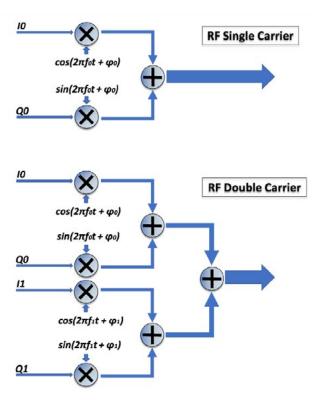


Digital IQ modulator with a single or double carrier (RF mode)

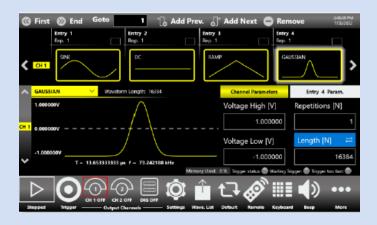
The RF mode gives a more advanced feature for creating and generating IQ modulated RF signals with a single or double carrier. This feature is available with all the T3AWG6K series platforms.

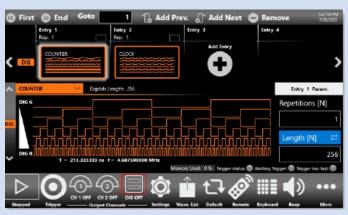
There are many applications where the RF mode is critical, starting from general applications, multi-channel arbitrary waveform generation, to satellite and radar testing, and ending with telecommunication I/Q communication signals.

With this internal IQ modulation feature, you do not need any more external modulators and mixers, so removing the cause of uncertainty for IQ mismatch, increasing the accuracy and the flexibility of the measurements. For every IQ component, it is possible select the shape of the waveform from the drop-down list, i.e waveform list, the amplitude, and the Voltage offset, while the Repetitions number and Length parameters will remain a specific setting of the entry. The sampling rate of the instrument for the RF mode pass from (up to) 6,16 GS/s of the Base Band mode, to (up to) 12,32 GS/s.



PRODUCT OVERVIEW





Waveform Sequencing with digital and analog synchronized signals

T3AWG6K can reproduce the signal in any case, whether you know how to define or can acquire the waveform. If you know how to define the waveform you can use the SW Waveform Editor utility that allows you to create the waveform in a simple, flexible, and affordable way.

If, on the other hand, the signal is acquired using a digital storage real-time oscilloscope, the waveform can be imported with simple steps into T3AWG6K arbitrary waveform generator and then played back as is or modified. But there is more. These waveforms can be a simple waveform entry into a more complex and articulated signal using the waveform sequencing.

In fact, the user can have up to 16,384 waveform entries of analog waveforms and digital patterns, define their execution flow by means of loops, jumps and conditional branches. Digital output combined and synchronized with analog output signals represent a must-have tool to troubleshoot and validate the modern mixed signal design including analog and synchronous digital signals. The waveform memory length is 4 GSamples for each channel to fit the most challenging applications.

In conclusion we can say that T3AWG6K arbitrary waveform generator represents an easy way to a seamless transition from simulation to generation for your lab.

Key Industries



Today's cars are including highly sophisticated electronic with very sensitive electronic components.

- 16-bit vertical voltage output resolution
- Waveform Sequencing adding noise and interference for EMI testing.
- Wide total output voltage window ±5 V or 10 V (into 50 Ohm)



Radar test and electronic warfare require to create specific complex true-to-life signals.

- Output RF signals directly up to 6 GHz (RF mode 12 GS/s)
- Built-in digital I/Q with a single or double carrier
- Wide output voltage ranges up to 5 V_{pp} and ±2.5 V HW Baseline Offset



Leading edge research in electronics physics, electronics, chemistry, mechanics, and other disciplines

- 4 GPts @Ch deep waveform memory
- Playback of signals acquired using the oscilloscope and imported into the T3AWG6K.
- Channel coupling for generating seamless phase related analog and digital signals.



Today's IC, components, and sensors are highly reliable extending the operating range in many variables.

- Separate or coupled per channel control of channel skew, frequency, gain, and offset.
- Signal BW up to 2.8 GHz BW per channel (6 GHz per channel in RF mode)
- Up to 32 digital channels synchronized with analog channels.

Automate your test and measurement requirements

Waveform generation for AFG and AWG operating modes and advanced remote instrument control

T3AWG6K series are easily added to your automated test environment. In addition to the programing manuals, which include the complete list of ASCII SCPI commands, programming examples are available for both the AFG (Function Generator) and AWG (Arbitrary Waveform Generator) operating modes. These programming examples make it easy to connect to a powerful graphi-

cal programming environment like LabView™, take full advantage of the visualization and programming capabilities found in MATLAB™, or use the flexibility offered by PYTHON or the .NET programming languages. Load waveforms, create sequences, change waveforms parameters, and enable signal generation directly from the PC.

General Specifications

	T3AWG6062	T3AWG6064	T3AWG6068
Number of Channels			<u>'</u>
Analog	2	4	8
Digital	0, 8	0, 8, 16	0, 8, 16, 32
Markers	1	2	4
Operating Modes			
Function Generator	AFG, Improved Direct D	igital Synthesizer (DDS) bas	sed Technology
Arbitrary Waveform Generator	AWG, Variable Clock "Tr	rue Arb" Technology	
Output Channels			
Output type	Single ended DC couple	ed	
Output impedance	Single ended: 50 Ω		
Connectors	SMA on front panel		
DC Amplitude			
Voltage Range	± 2.5 V (into 50 Ω)		
Resolution	100 μV (nom), 5 digits		
Amplitude Accuracy	± (1 % of setting + 5 m	V)	
DC Baseline Hardware Offset			
Range (50 Ω into 50 Ω)	-2.5 V to +2.5 V		
Range (50 Ω into High Impedance)	-2.5 V to +2.5 V		
DC Baseline Accuracy (50 Ω into 50 Ω)	± (1% of setting + 5 mV)		
AC Accuracy (1 kHz sine wave, 0 V offset, > 5 mV _{p-p} amplitude, 50 Ω load)	\pm (1% of setting [V _{pp}] + 5 mV) ¹⁾		

 $^{^{1)}}$ Specifications is valid in the range 0 % to 90 % of full scale output

AFG mode Specifications

	T3AWG6062	T3AWG6064	T3AWG6068	
General Specifications	<u>'</u>		'	
Operating Mode	Direct Digital Synthesi	zer (DDS)		
Sample Rate (SR)	6.16 GS/s (fixed)			
Amplitude Range	0 to 5 V _{pp} (into 50 Ω)			
Amplitude Resolution	100 μV (nom), 5 digits			
Run Modes	Continuous, modulation	Continuous, modulation, sweep, burst		
Standard Waveforms	Sine, Square, Pulse, Ramp, more (Noise, DC, Sin(x)/x, Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine			
Arbitrary Waveforms	Vertical resolution: 16-bit, Waveform length: 16,384 points			
Internal Trigger Timer	·			
Range	10.4 ns to 88 s			
Resolution	80 ps			
Accuracy	± (0.1% setting + 5 ps)			

Sine Waves Frequency Range Sine (50 0 into 50 0) 1 GHz to ≤ 1 GHz: 5 V _{np} 1 GHz to ≤ 2 GHz: 4 V _{po} 1 GHz to ≤ 2 GHz: 4 V _{po} 1 GHz to ≤ 2 GHz: 4 V _{po} 1 GHz to ≤ 2 GHz: 4 V _{po} 1 GHz to ≤ 2 GHz: 4 V _{po} 1 GHz to ≤ 2 GHz: 4 V _{po} 2 GHz: 4 V _{po} 1 GHz to ≤ 2 GHz: 4 V _{po} 2 GHz: 4 V _{po} 1 GHz to ≤ 2 GHz: 4 V _{po} 1 GHz to ≤ 2 GHz: 4 CHz to ≤ 2		T3AWG6062	T3AWG6064	T3AWG6068	
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Figure					
Flatness DC to 2 GHz: \pm 0.5 dB (1 V _{Pp} , relative to 1 kHz) Harmonic Distortion (1 V _{Pp}) 1 µHz to \pm 20 kHz < -70 dBc 400 MHz to \pm 1 GHz < -60 dBc 1 GHz to \pm 20 kHz < -70 dBc 400 MHz to \pm 1 GHz < -60 dBc 1 GHz to \pm 20 kHz < -70 dBc 400 MHz to \pm 1 GHz < -60 dBc 1 GHz to \pm 20 kHz < -70 dBc 500 MHz \pm 0.05 % Spurious (measured across 1 µHz to \pm 500 MHz < -75 dBc 500 MHz to \pm 1.5 GHz: < -70 dBc 1.5 GHz to \pm 2 GHz < -55 dBc Phase Noise (1 V _{Pp} , 10 kHz offset) 600 MHz to \pm 1.5 GHz to \pm 2 GHz < -55 dBc 700 MHz < -123 dBc/Hz typ. 100 MHz: < -124 dBc/Hz typ. 100 MHz: < -124 dBc/Hz typ. 100 MHz: < -127 dBc/Hz typ. 100 MHz: < -127 dBc/Hz typ. 100 MHz: < -120 dBc/Hz typ. 100 MHz: < -100 dBc/Hz typ. 100 MHz: < -10 dBc/Hz typ. 100 MHz: < -100 dBc/Hz t		1 μHz to ≤ 1 GHz: 5 V	[/] pp		
$ \begin{array}{lll} \text{Harmonic Distortion (1 V_{\text{PP}}$)} & 1 \ \mu\text{Hz to } \le 20 \ \text{kHz} < -76 \ \text{dBc} \\ 20 \ \text{kHz} < -76 \ \text{dBc} \\ 20 \ \text{kHz} < \times -76 \ \text{dBc} \\ 400 \ \text{MHz} \text{ to } \le 16 \ \text{Hz} < -60 \ \text{dBc} \\ \hline $	(50 Ω into 50 Ω) ¹⁾	1 GHz to ≤ 2 GHz: 4 \	$I_{ m pp}$		
20 kHz to ≤ 400 MHz < -70 dBc 400 MHz to ≤ 1 GHz < -60 dBc 1 GHz to ≤ 2 GHz < -55 dBc Total Harmonic Distortion (1 V _{p-p}) 10 Hz to ≥ 2 GHz < -55 dBc Total Harmonic Distortion (1 V _{p-p}) 10 Hz to ≥ 0 MHz (> -75 dBc Sou MHz to ≤ 1.5 GHz (> -70 dBc 1.5 GHz (Flatness	DC to 2 GHz: ± 0.5 dE	3 (1 V _{pp} , relative to 1 kHz)		
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Harmonic Distortion (1 V _{p-p})	1 μHz to ≤ 20 kHz < -	75 dBc		
1 GHz to ≤ 2 GHz < -55 dBc					
		400 MHz to ≤ 1 GHz	< -60 dBc		
Spurious (measured across DC to 3.08 Ghz) ²⁾ 1 μHz to ≤ 500 MHz: < -75 dBc		1 GHz to ≤ 2 GHz < -	55 dBc		
DC to 3.08 Ghz)² 500 MHz to ≤ 1.5 GHz: < -70 dBc	Total Harmonic Distortion (1 V _{p-p})	10 Hz to 20 kHz < 0.0	05 %		
1.5 GHz to ≤ 2 GHz: < -55 dBc Phase Noise (1 V _{P-P} , 10 kHz offset) 20 MHz: < -127 dBc/Hz typ. 100 MHz: < -123 dBc/Hz typ. 1 GHz: < -105 dBc/Hz typ. 1 GHz: < -105 dBc/Hz typ. Square Waves Frequency Range Sine (50 Ω into 50 Ω) 1 Rise/fall time (10 % to 90 %) 400 ps Rise/fall time (20 % to 80 %) 300 ps Overshoot (1 V _{P-P}) < 2 % Jitter (rms) < 2 ps Pulse Waves Frequency Range 1 μHz to ≤ 770 MHz Pulse width ® 500 ps to (Period − 500 ps) Pulse width Resolution 20 ps or 15 digits Pulse duty 0.1% to 99.9 % (limitations of pulse width apply) Leading/trailing edge transition time (10 % to 90 %) Leading/trailing edge transition time (20 % to 80 %) Transition time Resolution 2 ps or 15 digits Overshoot (1 V _{P-P}) < 2 % Jitter (rms, with rise and fall time ≥ 400 ps) - 2 ys - 3 ys (1 ys					
$\begin{array}{lll} Phase Noise \left(1 \ V_{P\text{-P}}, 10 \ \text{kHz} \ \text{offset}\right) & 20 \ \text{MHz}: < -127 \ \text{dBc/Hz} \ \text{typ.} \\ \hline 100 \ \text{MHz}: < -123 \ \text{dBc/Hz} \ \text{typ.} \\ \hline 1 \ \text{GHz}: < -105 \ \text{dBc/Hz} \ \text{typ.} \\ \hline \hline 1 \ \text{GHz}: < -105 \ \text{dBc/Hz} \ \text{typ.} \\ \hline \hline 1 \ \text{garge Sine} \\ \hline (50 \ \text{0} \ \text{into } 50 \ \text{Q})^{1)} & 1 \ \text{pHz} \ \text{to} \le 770 \ \text{MHz} \\ \hline \text{Rise/fall time} \left(10 \ \text{% to } 90 \ \text{%}\right) & 400 \ \text{ps} \\ \hline \text{Rise/fall time} \left(10 \ \text{% to } 80 \ \text{%}\right) & 300 \ \text{ps} \\ \hline \text{Overshoot} \left(1 \ \text{V}_{P\text{-p}}\right) & < 2 \ \text{%} \\ \hline \text{Jitter} \left(\text{rms}\right) & < 2 \ \text{ps} \\ \hline \text{Pulse Waves} \\ \hline \text{Frequency Range} & 1 \ \text{pHz} \ \text{to} \le 770 \ \text{MHz} \\ \hline \text{Pulse width}^{30} & 500 \ \text{ps to} \left(\text{Period} - 500 \ \text{ps}\right) \\ \hline \text{Pulse width}^{30} & 500 \ \text{ps to} \left(\text{Period} - 500 \ \text{ps}\right) \\ \hline \text{Pulse width}^{30} & 500 \ \text{ps to} \left(\text{Period} - 500 \ \text{ps}\right) \\ \hline \text{Pulse width}^{30} & 500 \ \text{ps to} \left(\text{Imitations of pulse width apply}\right) \\ \hline \text{Leading/trailing edge transition time} \\ \hline \left(10 \ \text{% to } 90 \ \text{%}\right) & 400 \ \text{ps to } 1,000 \ \text{s} \\ \hline \left(20 \ \text{% to } 80 \ \text{%}\right) \\ \hline \text{Transition time Resolution} & 2 \ \text{ps or } 15 \ \text{digits} \\ \hline \text{Overshoot} \left(1 \ \text{V}_{P\text{-p}}\right) & < 2 \ \text{%} \\ \hline \text{Jitter} \left(\text{rms}, \text{with rise and fall time} \right. & < 2 \ \text{ps} \\ \hline \\ \hline \text{20 buble Pulse Waves} \\ \hline \text{Frequency Range} & 1 \ \text{pHz} \ \text{to} \le 385 \ \text{MHz}: 10 \ \text{V}_{\text{pp}} \left(\text{V}_{\text{pp}} = \text{V}_{\text{pp}}1 + \text{V}_{\text{pp}}2 \right)} \\ \hline \text{Other Pulse Parameters} & \text{See Pulse Waves} \\ \hline \text{Ramp Waves} \\ \hline \end{array}$	DC to 3.08 Ghz) ²⁾	500 MHz to ≤ 1.5 GH	z: < -70 dBc		
$ \begin{array}{c c} 100 \text{ MHz: } < -123 \text{ dBc/Hz typ.} \\ \hline 1 \text{ GHz: } < -105 \text{ dBc/Hz typ.} \\ \hline \\ Square Waves \\ \hline \\ Frequency Range Sine \\ (50 0 into 50 0)^1 \\ \hline \\ Rise/fall time (10 \% to 90 \%) & 400 ps \\ \hline \\ Rise/fall time (20 \% to 80 \%) & 300 ps \\ \hline \\ Overshoot (1 V_{p-p}) & < 2 \% \\ \hline \\ Uitter (rms) & < 2 ps \\ \hline \\ Pulse Waves \\ \hline \\ Frequency Range & 1 \mu Hz to \le 770 \text{ MHz} \\ \hline \\ Pulse width ^{30} & 500 ps to (Period - 500 ps) \\ \hline \\ Pulse width Resolution & 20 ps or 15 digits \\ \hline \\ Pulse duty & 0.1 \% to 99.9 \% (limitations of pulse width apply) \\ \hline \\ Leading/trailing edge transition time (10 \% to 90 \%) & 300 ps to 1,000 s \\ \hline \\ (20 \% to 80 \%) & 300 ps to 1,000 s \\ \hline \\ \hline \\ Overshoot (1 V_{p-p}) & < 2 \% \\ \hline \\ Jitter (rms, with rise and fall time a 20 ps or 15 digits \\ \hline \\ $		1.5 GHz to ≤ 2 GHz: <	< -55 dBc		
Square Waves Frequency Range Sine (50 Ω into 50 Ω) ¹⁾ 1 μHz to ≤ 770 MHz Rise/fall time (10 % to 90 %) 400 ps Rise/fall time (20 % to 80 %) 300 ps Overshoot (1 V _P -p) < 2 %	Phase Noise (1 V _{p-p} , 10 kHz offset)	20 MHz: < -127 dBc/	Hz typ.		
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Jitter (rms) < 2 ps Pulse Waves Frequency Range	Rise/fall time (20 % to 80 %)	300 ps			
Pulse Waves1 μHz to ≤ 770 MHzPulse width 3 500 ps to (Period − 500 ps)Pulse width Resolution20 ps or 15 digitsPulse duty0.1% to 99.9 % (limitations of pulse width apply)Leading/trailing edge transition time (10% to 90%)400 ps to 1,000 sLeading/trailing edge transition time (20% to 80%)300 ps to 1,000 sTransition time Resolution2 ps or 15 digitsOvershoot (1 V _{P-P})< 2%	Overshoot (1 V _{p-p})	< 2 %			
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Pulse width Resolution 20 ps or 15 digits Pulse duty 0.1% to 99.9 % (limitations of pulse width apply) Leading/trailing edge transition time (10 % to 90 %) Leading/trailing edge transition time (20 % to 80 %) Transition time Resolution 2 ps or 15 digits Overshoot (1 V _{P-P}) < 2 % Jitter (rms, with rise and fall time ≥ 400 ps) Double Pulse Waves Frequency Range 1 µHz to ≤ 385 MHz: 10 V _{pp} (V _{pp} = V _{pp} 1 + V _{pp} 2) Other Pulse Parameters See Pulse Waves Ramp Waves	Frequency Range	1 µHz to ≤ 770 MHz			
Pulse duty 0.1% to 99.9% (limitations of pulse width apply) Leading/trailing edge transition time (10% to 90%) Leading/trailing edge transition time (20% to 80%) Transition time Resolution 2 ps or 15 digits Overshoot (1 V_{p-p}) < 2% Jitter (rms, with rise and fall time $\leq 400 \text{ ps}$) Double Pulse Waves Frequency Range 1 μ Hz to $\leq 385 \text{ MHz}$: 10 V_{pp} ($V_{pp} = V_{pp}1 + V_{pp}2 $) Other Pulse Parameters See Pulse Waves Ramp Waves	Pulse width ³⁾	500 ps to (Period – 5	500 ps)		
Leading/trailing edge transition time (10 % to 90 %) Leading/trailing edge transition time (20 % to 80 %) Transition time Resolution Overshoot (1 V_{p-p}) Jitter (rms, with rise and fall time $< 2 \text{ ps}$ $< 400 \text{ ps}$ Double Pulse Waves Frequency Range 1 μ Hz to $\le 385 \text{ MHz}$: $10 \text{ V}_{pp} \text{ (V}_{pp} = V_{pp}1 + V_{pp}2)}$ Other Pulse Parameters See Pulse Waves Ramp Waves	Pulse width Resolution	20 ps or 15 digits			
	Pulse duty	0.1% to 99.9% (limita	ations of pulse width apply)		
		400 ps to 1,000 s			
Overshoot (1 V_{p-p}) < 2 % Jitter (rms, with rise and fall time \geq 400 ps) < 2 ps \geq 400 ps) Double Pulse Waves Frequency Range		300 ps to 1,000 s			
Overshoot (1 V_{p-p}) < 2 % Jitter (rms, with rise and fall time $<$ 2 ps \geq 400 ps) Double Pulse Waves Frequency Range 1 μ Hz to \leq 385 MHz: 10 V_{pp} ($V_{pp} = V_{pp}1 + V_{pp}2 $) Other Pulse Parameters See Pulse Waves Ramp Waves	Transition time Resolution	2 ps or 15 digits			
Jitter (rms, with rise and fall time ≥ 400 ps)< 2 psDouble Pulse Waves1 μHz to ≤ 385 MHz: 10 V_{pp} ($V_{pp} = V_{pp}1 + V_{pp}2 $)Other Pulse ParametersSee Pulse WavesRamp Waves	Overshoot (1 V _{p-p})				
Frequency Range $1 \ \mu \text{Hz to} \le 385 \ \text{MHz:} \ 10 \ \text{V}_{pp} \ (\text{V}_{pp} = \text{V}_{pp}1 + \text{V}_{pp}2)$ Other Pulse Parameters See Pulse Waves Ramp Waves		< 2 ps			
Other Pulse Parameters See Pulse Waves Ramp Waves	Double Pulse Waves				
Other Pulse Parameters See Pulse Waves Ramp Waves	Frequency Range	1 µHz to ≤ 385 MHz:	$10 \text{ V}_{pp} (\text{V}_{pp} = \text{V}_{pp}1 + \text{V}_{pp}2)$		
Ramp Waves					
·					
rrequency range I µHZ to 75 MHZ	Frequency Range	1 μHz to 75 MHz			
Linearity (< 10 kHz, 1 V_{p-p} , 100 %) \leq 0.1%					
Symmetry 0 % to 100 %					

 $^{^{1)}}$ Amplitude doubles on High Impedance load $^{2)}$ Spurious are evaluated @1 Vpp single ended nominal output amplitude $^{3)}$ Below 500 ps width, the pulse amplitude will have some reduction respect to the set value

	T3AWG6062	T3AWG6064	T3AWG6068
Other Waves			
Frequency Range			
Exponential Rise, Exponential Decay	1 μHz to 75 MHz		
Sin(x)/x, Gaussian, Lorentz, Haversine	1 μHz to 150 MHz		
Additive Noise			
Bandwidth (-3 dB)	2 GHz		
Level	0 V to 2.5 V - abs (carr	ier max value [Vpk])	
Resolution	1 mV		
Frequency Resolution			
Sine, square, pulse, arbitrary, Sin(x)/X	1 μHz or 15 digits		
Gaussian, Lorentz, Exponential Rise, Exponential Decay, Haversine	1 μHz or 14 digits		
Frequency Accuracy			
Non-ARB	± 2.0 ppm of setting ±	500 ppb of setting (Opt.)	
ARB	± 2.0 ppm of setting ±1	μHz ± 500 ppb of setting ±1 μ	ıHz (Opt.)
Arbitrary			
Number of Samples	2 to 16,384		
Frequency range	1 μHz to ≤ 770 MHz		
Analog Bandwidth (-3 dB)	950 MHz		
Rise/fall time (10 % to 90 %)	400 ps		
Rise/fall time (20 % to 80 %)	300 ps		
Jitter (rms)	< 2 ps		

Modulations

Amplitude Modulation (AM)	
Carrier waveforms	Standard waveforms (except Pulse, DC and Noise), ARB
Modulation source	Internal or external
Internal modulating waveforms	Sine, Square, Ramp, Noise, ARB
Modulating frequency	Internal: 500 µHz to 61 MHz, External: 10 MHz max.
Depth	0.00 % to 120.00 %
Frequency Modulation (FM)	
Carrier waveforms	Standard waveforms (except Pulse, DC and Noise), ARB
Modulation source	Internal or external
Internal modulating waveforms	Sine, Square, Ramp, Noise, ARB
Modulating frequency	Internal: 500 µHz to 61 MHz, External: 10 MHz max.
Peak deviation	DC to 2 GHz
Phase Modulation (PM)	
Carrier waveforms	Standard waveforms (except Pulse, DC and Noise), ARB
Modulation source	Internal or external
Internal modulating waveforms	Sine, Square, Ramp, Noise, ARB
Modulating frequency	Internal: 500 µHz to 61 MHz, External: 10 MHz max.
Peak deviation range	0° to 360°

	T3AWG6062	T3AWG6064	T3AWG6068
	'	'	·
Frequency Shift Keying (FSK)			
Carrier waveforms	Standard waveforms (except Pulse, DC and Noise), ARB		
Modulation source	Internal or external		
Internal modulating waveforms	Square		
Key rate	Internal: 500 µHz to 6	1 MHz, External: 10 MHz max.	
Hop frequency	DC to 2 GHz		
Number of keys	2		
Phase Shift Keying (PSK)			
Carrier waveforms	Standard waveforms	(except Pulse, DC and Noise), AF	RB
Modulation source	Internal or external		
Internal modulating waveforms	Square		
Key rate	Internal: 500 µHz to 6	1 MHz, External: 10 MHz max.	
Hop frequency	0° to +360°		
Number of keys	2		
Pulse Width Modulation (PWM)			
Carrier waveforms	Pulse		
Modulation source	Internal or external		
Internal modulating waveforms	Sine, Square, Ramp, Noise, ARB		
Modulating frequency	Internal: 500 µHz to 6	1 MHz, External: 10 MHz max.	
Deviation range	0 % to 50 % of pulse p	eriod	
Sweep			
Туре	Linear, Logarithmic, st	taircase, and user defined	
Carrier waveforms	Standard waveforms	(except Pulse, DC and Noise), AF	RB
Sweep time	30 ns to 2,000 s		
Hold/return times	0 to (2000 s - 30 ns)		
Sweep/hold/return time resolution	15 ns or 12 digits		
Total sweep time accuracy	≤ 0.4 %		
Start/stop frequency range	Sine: 1 µHz to 2 GHz, Square: 1 µHz to 770 MHz		
Trigger source	Internal/External/Manual		
Burst			
Waveforms	Standard waveforms (except DC and Noise), ARB		
Туре	Trigger or gated		
Burst count	1 to 4,294,967,295 cycles or Infinite		

True Arb - Baseband mode Specifications

	T3AWG6062	T3AWG6064	T3AWG6068
General Specifications			
Operating Mode	Variable clock (True Arbitrary) – Baseband mode	
Sample Rate (SR)	1 S/s to 6.16 GS/s		
Sin(x)/x - 3 dB bandwidth	2.72 GHz @ 6.16 GS/S		
Run Modes	Continuous, Triggered Contin	uous, Sinale/Burst, Steppe	ed Advanced
Vertical Resolution	16 bit	idodo, omgie, barot, otopp	ea, navaneea
Max Waveform Length	4 G samples @channel		
Waveform Granularity	1 if the entry length is > 416 s	eamnles	
vaveronn Grandianty	32 if entry length is ≥ 128 and		
Sequence Length	1 to 16,384	2 - 10 3ampies	
Sequence Repeat Counter	1 to 4,294,967,294 or infinite		
	1 to 4,294,901,294 of fillillite		
Timer	00 1 100		
Range	20 ns to 1.39 seconds		
Resolution	± 1 sampling clock cycle		
Analog Channel to Channels skew			
Range	0 to 2.63 μs		
Resolution	100 fs		
Accuracy	± (1 % of setting + 20 ps)		
Initial Skew	< 20 ps		
Calculated bandwidth (0.35/rise time)	≥ 2 GHz		
SFDR @ 100 MHz ⁴⁾	< -80 dBc		
SFDR ⁴⁾	1 μHz to ≤ 600 MHz: < -80 dBc		
	600 MHz to ≤ 1.5 GHz: < -75 dBc		
	1.5 GHz to ≤ 2 GHz: < -65 dBo	2	
	2 GHz to ≤ 3 GHz: < -55 dBc		
Rise/fall time (1 V _{p-p} single-ended 10 % to 90 %)	≤ 175 ps		
Rise/fall time (1 V _{p-p} single-ended 20 % to 80 %)	≤ 110 ps		
Overshoot (1 V _{p-p} single-ended)	< 5 %		
Random jitter on clock pattern (rms, typical)	< 2 ps		
Timing and Clock			
Sampling Rate			
Range	1 S/s up to 6.16 GS/s		
Range in RF mode	1 S/s to 12.32 GS/S		
Resolution	32 Hz		
Accuracy	± 2.0 ppm		
Digital outputs (Optional)			
Output Channels			
Connectors	Mini-SAS HD connector on re	par panel (quetom pin-qut)	1
Number of connectors	1, 2, 4	car parier (edistorri piri odt))
Number of outputs	8-bits, 16-bits, 32-bits		
Output impedance	100 Ω differential		
Output type	LVDS		
Rise/fall time (10 % to 90 %)	< 1 ns		
Jitter (rms)	20 ps		
Maximum update rate	1.54 Gbps per channel		
Memory depth	1 GSamples per digital channel		

 $^{^{4)}}$ Measured across DC to Fs/2, excluding fsa -2* fout and fsa -3* fout and excluding harmonic where Fsa = 6.16 Gsa/s.

True Arb - RF mode Specifications

	T3AWG6062	T3AWG6064	T3AWG6068	
General Specifications				
Operating Mode	Variable clock (True Arbitrary) – RF mode			
Output Sample Rate (SR)	8.5 GS/s to 12.32 GS/	's		
Sin(x)/x -3 dB bandwidth	5.04 Ghz @ 12.32 GS/	/S		
RF Modulation	I/Q quadrature			
RF Carrier count per output channel	Single Carrier (2 comp	oonents I0, Q0 for channel)		
	Double Carrier (4 com	ponents, IO, QO and I1, Q1 for ch	annel)	
RF Carrier Frequency range	0 up to 6 GHz			
RF Carrier Frequency resolution	1 mHz			
RF Carrier Phase	Programmable			
I/Q Component Data Rate	1/8 of the Output Sam	nple rate		
I/Q Component Prescaler	0 to 2^32			
Run Modes	Continuous, Triggered	Continuous, Triggered Continuous, Single/Burst, Stepped, Advanced		
I/Q Component Vertical Resolution	16 bit	16 bit		
I/Q Component Waveform Length	32 M to 500 M samples for component (up to 1 G samples)			
I/Q Component Waveform Granularity	1 if the entry length is	> 104 samples		
	8 if entry length is ≥ 3	2 and ≤ 104 samples		
Sequence Length	1 to 16,384			
Sequence Repeat Counter	1 to 4,294,967,294 or	infinite		
Timer				
Range	20 ns to 1.39 seconds	3		
Resolution	± 1 Component sampling clock cycle			
I/Q Component to Component skew				
Range	0 to [16,200 * 8/Output Sampling Clock] s			
Resolution	[8/Output Sampling Clock] s			
Accuracy	± (1 % of setting + 20 ps)			
Initial Skew	< 20 ps			

Auxiliary input and output characteristics

	T3AWG6062	T3AWG6064	T3AWG6068
Sync in/out			
Connector type	Infiniband 4X connecte	or on rear panel (custom pinout)	
Master to Slave delay (typ.)	TBD		
Marker Output			
Connector type	SMA on front panel		
Number of connectors	1/2/4		
Output impedance	50 Ω		
Output level (into 50 Ω)			
Voltage Window Amplitude	-0.5 V to 1.65 V		
Voltage Resolution	100 mV _{pp} to 2.15 V _{pp}		
Voltage Accuracy	1 mV ± (5 % setting + 2	25 mV)	
Switching characteristics			
Max Update Rate (True Arb Mode)	6.16 Gbps		
Max Frequency (AFG Mode)	96.5 MHz (continuous	mode)	
Rise/Fall Time (10 % to 90 %, 2 V _{pp})	< 150 ps		
Jitter (rms)	< 10 ps		
Marker out to analog channel skew			
Range	True Arb Mode: 0 to 2.	3 µs	
	AFG Mode: 0 to 11 sec	c. in Contin. Mode, 0 to 2.3 µs in 1	Trig. Mode
Resolution	True Arb Mode: 1/64 c	f DAC sampling period	
	AFG Mode: 5 ps		
Accuracy	± (1% of setting + 5 ps)	
Initial skew	< 20 ps		
Trigger/Event Inputs			
Connector	SMA on the Front Pan	el	
Number of Trigger Inputs	2 (Trig.in 1, Trig.in 2)		
Input impedance	50 Ω / 1 kΩ		
Slope/Polarity	Positive or negative or	both	
Input damage level	< -15 V or > +15 V		
Threshold control level	-10 V to 10 V		
Resolution	50 mV		
Threshold control accuracy	± (10 % of setting + 0	.2 V)	
Input voltage swing	0.5 V _{p-p} minimum		
Minimum pulse width (1 V _{p-p})	3 ns		
Trigger/gate input to Analog Output de	lay		
Slow (synchronous) trigger		: 405 ns in triggered sweep mode	e)
	True Arb mode: < 1550) * DAC clock period(ns) + 10 ns	
Fast (asynchronous) trigger	AFG mode: < 335 ns (< 385 ns in triggered sweep mode)		
		0 * DAC clock period(ns) + 27 ns	
Trigger In to output jitter (rms)	AFG mode: < 20 ps		
· · ·	True Arb mode: 0.29 *	DAC clock period	
Trigger In programmable delay range	0 ps to 2,418 ps		
Trigger In programmable delay resolution	78 ps		
Maximum Frequency	AFG: 65 MTps on Risir	ng/Falling Edge, 80 MTps on Both	n Edges
	True Arb mode: 1 / (Period of the Analog Waveform + 48 DAC clock period)		
	MTps = Mega Transitions per second		

	T3AWG6062	T3AWG6064	T3AWG6068	
Reference clock input				
Connector type	SMA on rear panel			
Input impedance	50 Ω, AC coupled			
Input voltage range	0.2 V _{pp} to 2 V _{pp}			
Damage level	Maximum Input voltage			
	Maximum input powe	r: 30 dBm (50 Ω)		
Frequency range	5 MHz to 200 MHz			
Frequency Resolution	1 Hz			
Reference clock output				
Connector type	SMA on rear panel			
Output impedance	50 Ω, AC coupled			
Frequency	10 MHz TCX0 100 M	Hz VCOCXO (Optional)		
Initial accuracy @ 25 °C	± 1.0 ppm			
Aging	± 1.0 ppm/year			
Stability vs. temperature	± 1 ppm			
Amplitude	1.65 V _{pp}			
Phase Noise @ 20 MHz carrier	-120 dBc/Hz at 100 H	z; -140 dBc/Hz at 1 KHz; -150	dBc/Hz at 10 KHz	
Phase Noise @ 100 MHz carrier	-120 dBc/Hz at 100 H	z; -145 dBc/Hz at 1 KHz; -150	dBc/Hz at 10 KHz	
External Clock Input				
Connector type	SMA on rear panel			
Input impedance	50 Ω, AC coupled			
Frequency ⁵⁾	True Arb: SampleRate	/ N where:		
	N = 4, 8, 16, 32 and SampleRate = 3.08 ÷ 6.16 GSps			
		N = 2, 4, 8, 16, 32 and SampleRate = 3.08 ÷ 5.0 GSps		
	N = 2, 4, 8, 16 and SampleRate = 1.54 ÷ 3.08 GSps N = 1, 2, 4, 8, 16 and SampleRate = 1.54 ÷ 2.5 GSps			
		<u> </u>		
		MHz, 770 MHz or 1,540 MHz (s	electable)	
Input Power Range	+0 dBm to +10 dBm			
Damage Level	15 dBm			
Sync Clk Out				
Connector type	SMA on rear panel			
Output impedance	50 Ω, AC coupled			
Frequency		N where N = 16, 32, 64,, 2,04		
		ling Rate / N, N = 16, 32,, 2,04	18	
Amplitude	1V _{pp} into 50 Ω			
External Modulation input				
Connector type	SMA on rear panel			
Input impedance	10 ΚΩ			
Number of inputs	1			
Bandwidth	10 MHz with 50 MS/s	sampling rate		
Input voltage range	-1 V to +1 V (except F	SK, PSK)		
	FSK, PSK: 0 V ÷ 3.3 V	with 1.65 V fixed threshold		
Vertical resolution	12-bit			
Pattern Jump In (optional)				
Connector type	DSUB15			
Input signals	DATA [07] + Data_Select + Load			
Internal Data Width	14 bit, multiplexed using Data_Select			
Number of addressable entries	16,384			
Data Rate	DC to 1 MHz			
Input Range	VIL = 0 V to 0.8 V / VIH= 2 V to 3.3 V			
Impedance	Internal 1 k Ω pull-up resistor to Vcc (3.3 V)			
	- F 3P .	\ /-		

 $^{^{5)}}$ When using the External Clock Input the SampleRate must be in the range 3.08 \div 6.16 GHz

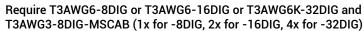
Power / Environmental characteristics / EMC and safety

	T3AWG6062	T3AWG6064	T3AWG6068	
Power				
Source Voltage and Frequency	100 to 240 VAC ±10 % @	45-66 Hz		
Max. power consumption	Max. 100 W (T3AWG606	2)		
	Max. 200 W (T3AWG6064)			
	Max. 300 W (T3AWG6068)			
Environmental characteristics				
Temperature (operating)	+5 °C to +40 °C (+41 °F to 104 °F)			
Temperature (non-operating)	-20 °C to +60 °C (-4 °F to 140 °F)			
Humidity (operating)	5 % to 80 % relative humidity with a maximum wet bulb temperature of 29 °C at or below +40 °C, (upper limit de-rates to 20.6 % relative humidity at +40 °C).			
Humidity (non-operating)	5 % to 95 % relative humidity with a maximum wet bulb temperature of 40 °C at or below +60 °C, upper limit de-rates to 29.8 % relative humidity at +60 °C. Non-condensing.			
Altitude (operating)	3,000 meters (9,842 feet) maximum at or below 25 °C			
Altitude (non-operating)	12,000 meters (39,370 feet) maximum			
EMC and safety				
Safety	EN61010-1			
Main Standards	EN 61326-1:2013 – Electrical equipment for measurement, control and laboratory use – EMC requirements – Part 1: General requirements			
Immunity	EN 61326-1:2013			

System specifications

	T3AWG6062	T3AWG6064	T3AWG6068	
Display	7 inch, 1024 x 600, capacitive touch LCD			
Operative System	Windows 10			
External Dimensions	W 445 mm – H 135 mm – D 320 mm (3U 19" rackmount)			
Weight	Max. 26.45 lbs (12 Kg)			
Front panel connectors	CH N OUTPUT (SMA) where N = 2, 4,8 depending on the model			
Trent parter commencer	MARKER N OUT (SMA) where N = 1, 2,4 depending on the model			
	TRIGGER IN N (SMA) where N = 1,2			
	2 USB 3.0 ports			
Rear panel connectors	Ref. Clk. IN (SMA)			
·	Ref. Clk. Out (SMA)			
	Ext. Mod. IN (SMA)			
	Sync Clk Out (SMA)			
	Ext Clk IN (SMA)			
	Sync IN (Infiniband 4X)			
	Sync OUT (Infiniband 4X)			
	POD X [70] where X = A, B, C, D depending on the model (Customized Mini SAS HD)			
	External Monitor ports (one or more)			
	2 USB 2.0 ports or more			
	4 USB 3.0 ports			
	Ethernet port (10/100/1000BaseT Ethernet, RJ45 port)			
	2 PS/2 keyboard and mouse ports			
	2 DPI ports			
	1 DVI port			
Hard Disk	1 TB SSD or better			
Processor	Intel® Pentium 3.7 GHz (or better)			
Processor Memory	32 GB or better			

T3AWG3-8DIG-TTL LVDS to LVTTL adapter





Output Connector	20 position 2.54 mm 2 Row IDC Header		
Output Type	LVTTL		
Output Impedance	50 Ω nominal		
Output voltage	0.8 V to 3.8 V programmable in group og 8 bits		
Maximum update rate	125 Mbps@0.8 V and 400 Mbps@3.6 V		
Dimension	W 52 mm - H 22 mm - D 76 mm		
Input connectors	proprietary standard		
Cable length	1 meter		
Cable type	proprietary standard		

T3AWG3-8DIG-SMA Mini-SAS HD to 16x SMA cable (8 LVDS outputs)

Require T3AWG6-8DIG or T3AWG6-16DIG or T3AWG6K-32DIG



Output Connector	SMA
Output Type	LVDS
Number of SMA	16 (8 bits)
Cable length	1 meter
Cable type	proprietary standard

Digital Channels Selection Guide

	8 Digital Channels	16 Digital Channels	32 Digital Channels		
Digital Options	T3AWG6-8DIG	T3AWG6-16DIG	T3AWG6-32DIG		
Product Mainframe					
T3AWG6062	Yes	No	No		
T3AWG6064	Yes	Yes	No		
T3AWG6068	Yes	Yes	Yes		
Accessories required:					
Cable mini SAS HD 1 m	1 x T3AWG3-8DIG-MSCAB	2 x T3AWG3-8DIG-MSCAB	4 x T3AWG3-8DIG-MSCAB		
LVTTL digital output 1)	1 x T3AWG3-8DIG-TTL	2 x T3AWG3-8DIG-TTL	4 x T3AWG3-8DIG-TTL		
mini SAS HD to x16 SMA Cable	1 x T3AWG3-8DIG-SMA	2 x T3AWG3-8DIG-SMA	4 x T3AWG3-8DIG-SMA		

¹⁾ LVTTL digital output requires Cable mini SAS

Ordering information

T3AWG6062 Product Description (2 Channel platform)	Product Code
Arbitrary Waveform Generator, 2 CH, 6 GS/s, 4,096 Mpts/Ch, 5 Vpp, RF mode (12 GS/s),	T3AWG6062
Wave Sequencing	
8 Digital Output Channels for 2 CH, 4 CH and 8 CH T3AWG6K models (require 1 x Mini-SAS cable)	T3AWG6-8DIG
T3AWG6064 Product Description (4 Channel platform)	Product Code
Arbitrary Waveform Generator, 4 CH, 6 GS/s, 4,096 Mpts/Ch, 5 Vpp, RF mode (12 GS/s),	T3AWG6064
Wave Sequencing	
8 Digital Output Channels for 2 CH, 4 CH and 8 CH T3AWG6K models (require 1 x Mini-SAS cable)	T3AWG6-8DIG
16 Digital Output Channels for 4 CH and 8 CH T3AWG6K models (require 2 x Mini-SAS cable)	T3AWG6-16DIG
T3AWG6068 Product Description (8 Channel platform)	Product Code
Arbitrary Waveform Generator, 8 CH, 6 GS/s, 4,096 Mpts/Ch, 5 Vpp, RF mode (12 GS/s), Wave Sequencing	T3AWG6068
8 Digital Output Channels for 2 CH, 4 CH and 8 CH T3AWG6K models (require 1 x Mini-SAS cable)	T3AWG6-8DIG
16 Digital Output Channels for 4 CH and 8 CH T3AWG6K models (require 2 x Mini-SAS cable)	T3AWG6-16DIG
32 Digital Output Channels for 8 CH T3AWG6K models (require 4 x Mini-SAS cable)	T3AWG6-32DIG
Accessories for all platforms (2, 4 and 8 Channels)	Product Code
Cable Mini SAS HD 1 m for DIG options (1x for -8DIG, 2x for -16DIG, 4x for -32DIG)	T3AWG3-8DIG-MSCAB
LVDS to LVTTL adapter ¹⁾	T3AWG3-8DIG-TTL
Mini-SAS HD to 16 x SMA cable (8 LVDS output) ²⁾	T3AWG3-8DIG-SMA
Additional SSD – 500 GB	T3AWG3-SSD
3U – 19" RACKMOUNT KIT for T3AWG6K	T3AWG-RACKMOUNT-X

 $^{^{1)}}$ require T3AWG6-8DIG or T3AWG6-16DIG or T3AWG6K-32DIG and T3AWG3-8DIG-MSCAB (1x for -8DIG, 2x for -16DIG, 4x for -32DIG) require T3AWG6-8DIG or T3AWG6-16DIG or T3AWG6K-32DIG

Standard warranty is one year.

ABOUT TELEDYNE TEST TOOLS



Company Profile

Teledyne LeCroy is a leading provider of oscilloscopes, protocol analyzers and related test and measurement solutions that enable companies across a wide range of industries to design and test electronic devices of all types. Since our founding in 1964, we have focused on creating products that improve productivity by helping engineers resolve design issues faster and more effectively. Oscilloscopes are tools used by designers and engineers to measure and analyze complex electronic signals in order to develop high-performance systems and to validate electronic designs in order to improve time to market.

The Teledyne Test Tools brand extends the Teledyne LeCroy product portfolio with a comprehensive range of test equipment solutions. This new range of products delivers a broad range of quality test solutions that enable engineers to rapidly validate product and design and reduce time-to-market. Designers, engineers and educators rely on Teledyne Test Tools solutions to meet their most challenging needs for testing, education and electronics validation.

Location and Facilities

Headquartered in Chestnut Ridge, New York, Teledyne Test Tools and Teledyne LeCroy has sales, service and development subsidiaries in the US and throughout Europe and Asia. Teledyne Test Tools and Teledyne LeCroy products are employed across a wide variety of industries, including semiconductor, computer, consumer electronics, education, military/aerospace, automotive/industrial, and telecommunications.

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